

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

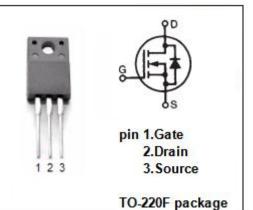
AOTF8T50P

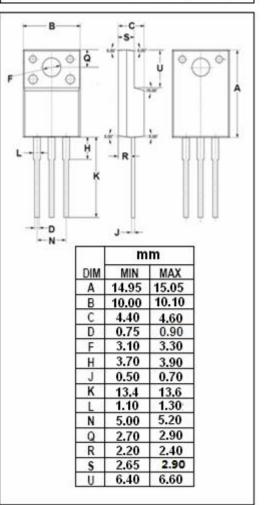
FEATURES

- Drain Current $-I_D$ =8A@ T_C =25 $^{\circ}C$
- Drain Source Voltage-
- : V_{DSS}=500V(Min)
- Static Drain-Source On-Resistance : R_{DS(on)} =0.81 Ω (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.





ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT | | | |
|------------------|---|-------|------|--|--|--|
| V _{DSS} | Drain-Source Voltage | 500 | V | | | |
| V _{GS} | Gate-Source Voltage-Continuous | ±30 | V | | | |
| I _D | Drain Current-Continuous | 8 | A | | | |
| I _{DM} | Drain Current-Single Pluse | 32 | A | | | |
| P _D | Total Dissipation @T _c =25℃ | 38 | W | | | |
| TJ | Max. Operating Junction Temperature -55~150 | | Ĉ | | | |
| T _{stg} | Storage Temperature -55~150 | | °C | | | |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|--------------------------------------|-----|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 3.3 | °C/W |



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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | МАХ | UNIT |
|----------------------|---------------------------------|---|-----|---------|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 0.25mA | 500 | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} = 5V; I _D = 0.25mA | 3.0 | 5.0 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D =4A | | 0.81 | Ω |
| lgss | Gate-Body Leakage Current | V _{GS} = ±30V;V _{DS} = 0 | | ±100 | nA |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =500V; V _{GS} = 0 V _{DS} =400V; V _{GS} = 0@T _J =125℃ | | 1 10 | μA |
| V _{SD} | Forward On-Voltage | I _S = 1A; V _{GS} = 0 | | 1 | V |



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